

PUBLICATION NUMBER : 01291401
PUBLICATION DATE : 24-11-89

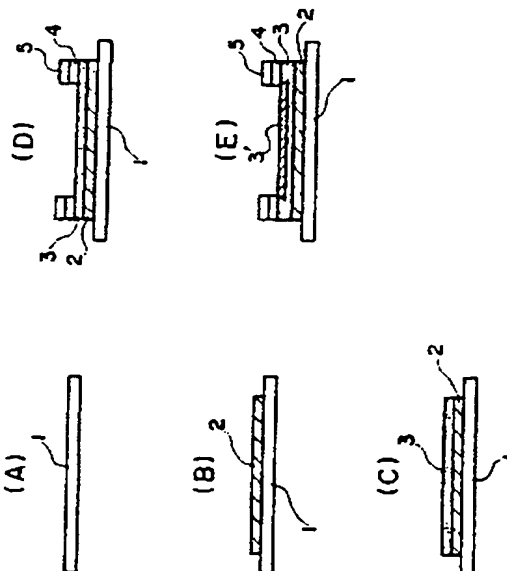
APPLICATION DATE : 19-05-88
APPLICATION NUMBER : 63120423

APPLICANT : FUJI ELELCTROCHEM CO LTD;

INVENTOR : INOUE JUNICHI;

INT.CL. : H01C 7/00 C23C 14/06 H01C 17/12

TITLE : THIN FILM RESISTOR AND
MANUFACTURE THEREOF



ABSTRACT : PURPOSE: To obtain a thin film resistor whose temperature coefficient is almost zero and which enables reducing the equipment cost and the product manufacturing cost, by laminating a tantalum nitride film of a negative temperature coefficient and an α-tantalum film of a positive temperature coefficient on an alumina substrate, and by canceling both temperature coefficients each other out.

CONSTITUTION: A Ta₂N film 2 is formed on an alumina substrate 1, and an α-Ta film 3 of bcc structure is formed on this Ta₂N film 2. After that, electrodes comprising compound films of NiCr alloys 4 and Au 5 are attached to the α-Ta film 3. Then, they are heat-treated along with the electrodes in the atmosphere kept at 300°C, and a tantalum pentoxide film 3' is formed by oxidizing the surface of the part of the α-Ta film 3 where the electrodes are not attached. At this time, a part of them is connected with lead wires as a monitor to a resistance value measuring device outside of the heat-treating device, and they are simultaneously heat-treated until the temperature coefficient of the monitor becomes zero. In this way, a plurality of thin film resistors whose temperature coefficients are zero are obtained at the same time.

COPYRIGHT: (C)1989,JPO&Japio